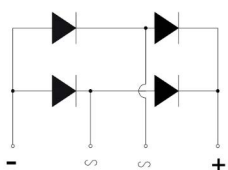
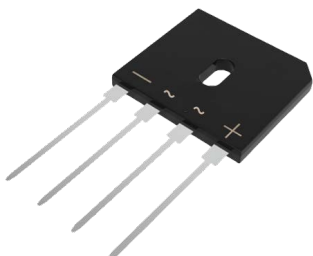


Low VF Bridge Rectifiers



Features

- Glass Passivated Chip Junction
- Low IRRM
- Low VF
- High VRRM

Benefits

- Case: GBU
- Terminals: Solderable Per MIL-STD-750
- Reduced power loss and switching transistor
- Reduced snubbing

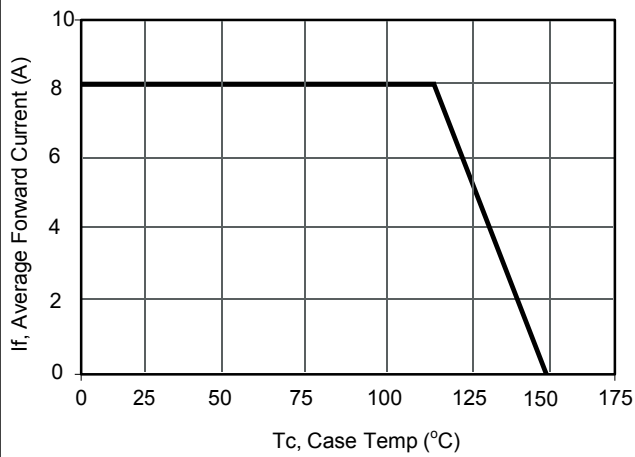
Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

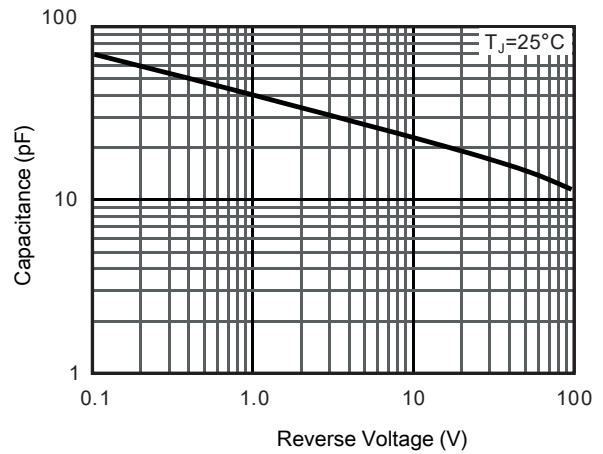
Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	GBU8L06	Units
Maximum Repetitive Peak Reverse Voltage	VRRM	600	V
Maximum RMS voltage	VRMS	420	V
Maximum DC Blocking Voltage	VDC	600	V
Average Rectified Output Current	Io	8.0	A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	IFSM	120	A
Maximum Forward Voltage at 4.0 A	VF	0.90	V
Maximum DC Reverse Current @TA=25 °C at Rated DC Blocking Voltage @TA=125 °C	IR	5 100	μA
Typical Junction Capacitance (Note1)	Cj	25	pF
Operating and Storage Temperature Range	Tj, Tstg	-55 ~ +150	°C
Note: 1. Measured at 1MHz and applied reverse voltage of 4 VDC. 2. Mounted on glass epoxy PC board with 4 × 1.5 ± 1.5 (3.81 × 3.81 cm) copper pad			

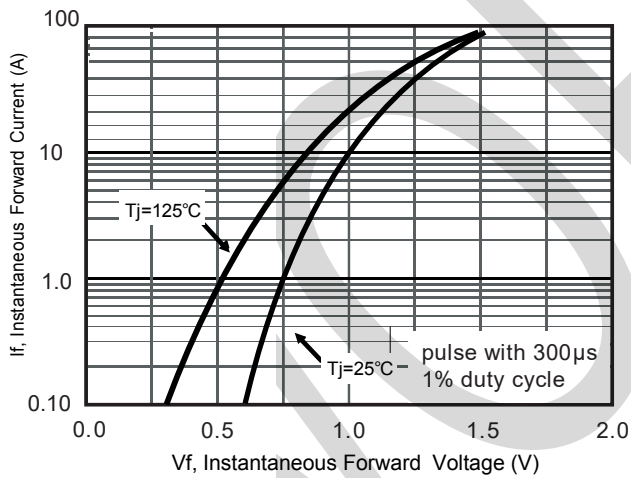
RATINGS AND CHARACTERISTICS CURVES (TA = 25 °C unless otherwise noted)



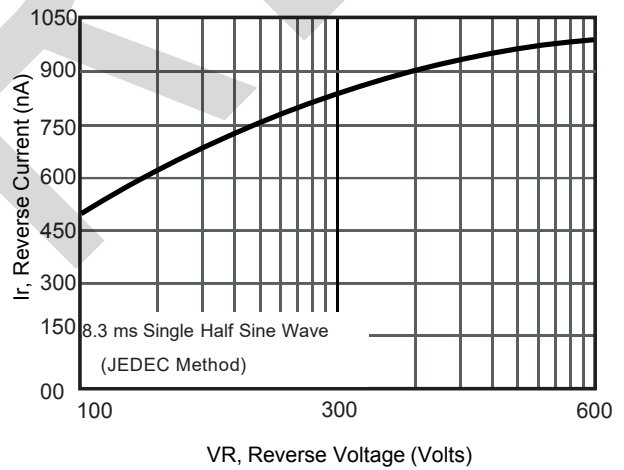
Current Derating, Case



Typical Junction Capacitance

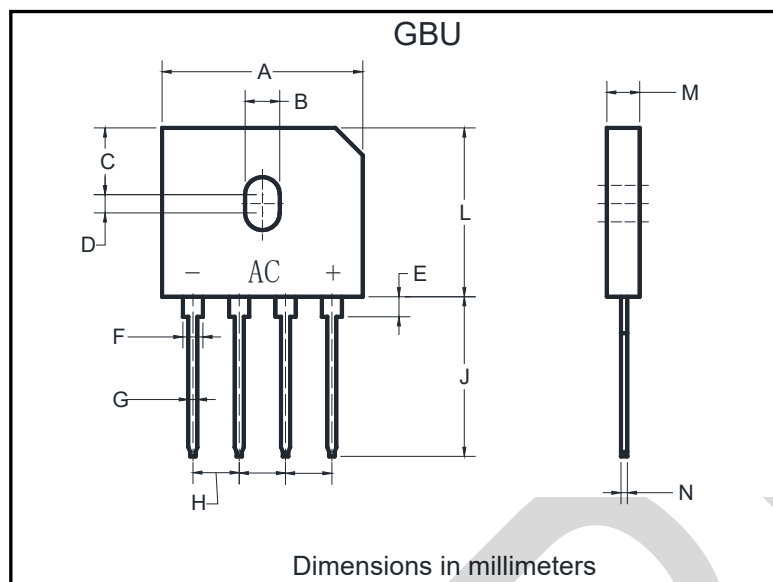


Typical Forward Voltage



Typical Reverse Current

PACKAGE OUTLINE DIMENSIONS



GBU		
Dim	Min	Max
A	21.70	22.50
B	3.40	4.10
C	7.40	8.00
D	1.65	2.26
E	2.25	2.85
F	2.05	2.4
G	1.02	1.37
H	4.83	5.43
J	17.0	18.6
L	18.3	18.9
M	3.30	3.66
N	0.46	0.66

